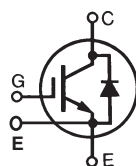


### High Voltage, High Gain BIMOSFET™ Monolithic Bipolar MOS Transistor

### IXBN42N170A



$$V_{CES} = 1700V$$

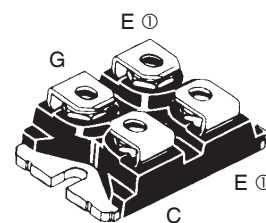
$$I_{C90} = 21A$$

$$V_{CE(sat)} \leq 6.0V$$

$$t_{fi} = 20ns$$

SOT-227B, miniBLOC

 E153432



G = Gate, C = Collector, E = Emitter

① either emitter terminal can be used as Main or Kelvin Emitter

| Symbol                        | Test Conditions                                                                               | Maximum Ratings       |      |            |
|-------------------------------|-----------------------------------------------------------------------------------------------|-----------------------|------|------------|
| $V_{CES}$                     | $T_C = 25^\circ C$ to $150^\circ C$                                                           | 1700                  |      | V          |
| $V_{CGR}$                     | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GE} = 1M\Omega$                                     | 1700                  |      | V          |
| $V_{GES}$                     | Continuous                                                                                    | $\pm 20$              |      | V          |
| $V_{GEM}$                     | Transient                                                                                     | $\pm 30$              |      | V          |
| $I_{C25}$                     | $T_C = 25^\circ C$                                                                            | 38                    |      | A          |
| $I_{C90}$                     | $T_C = 90^\circ C$                                                                            | 21                    |      | A          |
| $I_{CM}$                      | $T_C = 25^\circ C$ , 1ms                                                                      | 265                   |      | A          |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ C$ , $R_G = 10\Omega$<br>Clamped Inductive Load          | $I_{CM} = 84$<br>1360 |      | A<br>V     |
| $T_{SC}$<br><b>(SCSOA)</b>    | $V_{GE} = 15V$ , $V_{CES} = 1200V$ , $T_J = 125^\circ C$<br>$R_G = 10\Omega$ , non repetitive | 10                    |      | $\mu s$    |
| $P_C$                         | $T_C = 25^\circ C$                                                                            | 313                   |      | W          |
| $T_J$                         |                                                                                               | -55 ... +150          |      | $^\circ C$ |
| $T_{JM}$                      |                                                                                               | 150                   |      | $^\circ C$ |
| $T_{stg}$                     |                                                                                               | -55 ... +150          |      | $^\circ C$ |
| $V_{ISOL}$                    | 50/60Hz                                                                                       | t = 1min              | 2500 | V~         |
|                               | $I_{ISOL} \leq 1mA$                                                                           | t = 1s                | 3000 | V~         |
| $M_d$                         | Mounting Torque                                                                               | 1.5/13                |      | Nm/lb.in.  |
|                               | Terminal Connection Torque                                                                    | 1.3/11.5              |      | Nm/lb.in.  |
| <b>Weight</b>                 |                                                                                               | 30                    |      | g          |

#### Features

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Square RBSOA
- 2500V~ Isolation Voltage
- High Blocking Voltage
- International Standard Package
- Anti-Parallel Diode
- Low Conduction Losses

#### Advantages

- Low Gate Drive Requirement
- High Power Density

#### Applications

- Switch-Mode and Resonant-Mode Power Supplies
- Uninterruptible Power Supplies (UPS)
- AC Motor Drives
- Capacitor Discharge Circuits
- AC Switches

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values |      |                      |
|---------------|---------------------------------------------------------------------|-----------------------|------|----------------------|
|               |                                                                     | Min.                  | Typ. | Max.                 |
| $BV_{CES}$    | $I_C = 250\mu A$ , $V_{GE} = 0V$                                    | 1700                  |      | V                    |
| $V_{GE(th)}$  | $I_C = 750\mu A$ , $V_{CE} = V_{GE}$                                | 2.5                   |      | 5.5 V                |
| $I_{CES}$     | $V_{CE} = 0.8 \cdot V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 125^\circ C$ |                       |      | 50 $\mu A$<br>1.5 mA |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                  |                       |      | $\pm 100$ nA         |
| $V_{CE(sat)}$ | $I_C = I_{C90}$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 125^\circ C$    |                       | 5.2  | 6.0 V                |
|               |                                                                     |                       | 5.3  | V                    |

## Symbol Test Conditions

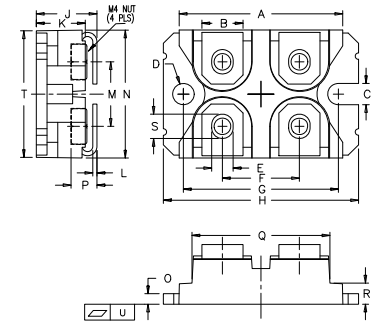
( $T_J = 25^\circ\text{C}$  Unless Otherwise Specified)

## Characteristic Values

Min. Typ. Max.

|              |                                                                                                                                                                                |      |      |                         |
|--------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|-------------------------|
| $g_{fs}$     | $I_C = I_{C90}, V_{CE} = 10V, \text{Note 1}$                                                                                                                                   | 14   | 23   | S                       |
| $C_{ies}$    | $V_{CE} = 25V, V_{GE} = 0V, f = 1\text{MHz}$                                                                                                                                   |      | 3920 | pF                      |
| $C_{oes}$    |                                                                                                                                                                                |      | 275  | pF                      |
| $C_{res}$    |                                                                                                                                                                                |      | 107  | pF                      |
| $Q_{g(on)}$  | $I_C = I_{C90}, V_{GE} = 15V, V_{CE} = 0.5 \cdot V_{CES}$                                                                                                                      |      | 188  | nC                      |
| $Q_{ge}$     |                                                                                                                                                                                |      | 23   | nC                      |
| $Q_{gc}$     |                                                                                                                                                                                |      | 80   | nC                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = I_{C90}, V_{GE} = 15V$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 1\Omega$<br>Diode Type = DH40-18A<br>Note 2  |      | 19   | ns                      |
| $t_{ri}$     |                                                                                                                                                                                |      | 17   | ns                      |
| $E_{on}$     |                                                                                                                                                                                |      | 3.43 | mJ                      |
| $t_{d(off)}$ |                                                                                                                                                                                |      | 200  | ns                      |
| $t_{fi}$     |                                                                                                                                                                                |      | 20   | ns                      |
| $E_{off}$    |                                                                                                                                                                                |      | 0.43 | mJ                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = I_{C90}, V_{GE} = 15V$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 1\Omega$<br>Diode Type = DH40-18A<br>Note 2 |      | 19   | ns                      |
| $t_{ri}$     |                                                                                                                                                                                |      | 14   | ns                      |
| $E_{on}$     |                                                                                                                                                                                |      | 5.40 | mJ                      |
| $t_{d(off)}$ |                                                                                                                                                                                |      | 226  | ns                      |
| $t_{fi}$     |                                                                                                                                                                                |      | 82   | ns                      |
| $E_{off}$    |                                                                                                                                                                                |      | 0.83 | mJ                      |
| $R_{thJC}$   |                                                                                                                                                                                |      |      | 0.40 $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                                                | 0.05 |      | $^\circ\text{C/W}$      |

## SOT-227B miniBLOC (IXXN)



| SYM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 1.240  | 1.255 | 31.50       | 31.88 |
| B   | .307   | .323  | 7.80        | 8.20  |
| C   | .161   | .169  | 4.09        | 4.29  |
| D   | .161   | .169  | 4.09        | 4.29  |
| E   | .161   | .169  | 4.09        | 4.29  |
| F   | .587   | .595  | 14.91       | 15.11 |
| G   | 1.186  | 1.193 | 30.12       | 30.30 |
| H   | 1.496  | 1.505 | 38.00       | 38.23 |
| J   | .460   | .481  | 11.68       | 12.22 |
| K   | .351   | .378  | 8.92        | 9.60  |
| L   | .030   | .033  | 0.76        | 0.84  |
| M   | .496   | .506  | 12.60       | 12.85 |
| N   | .990   | 1.001 | 25.15       | 25.42 |
| O   | .078   | .084  | 1.98        | 2.13  |
| P   | .195   | .235  | 4.95        | 5.97  |
| Q   | 1.045  | 1.059 | 26.54       | 26.90 |
| R   | .155   | .174  | 3.94        | 4.42  |
| S   | .186   | .191  | 4.72        | 4.85  |
| T   | .968   | .987  | 24.59       | 25.07 |
| U   | -.002  | .004  | -0.05       | 0.1   |

## Reverse Diode

## Symbol Test Conditions

( $T_J = 25^\circ\text{C}$  Unless Otherwise Specified)

## Characteristic Values

Min. Typ. Max.

|          |                                                |  |     |    |
|----------|------------------------------------------------|--|-----|----|
| $V_F$    | $I_F = I_{C90}, V_{GE} = 0V$                   |  | 5.0 | V  |
| $t_{rr}$ | $I_F = 25A, V_{GE} = 0V, -di_F/dt = 50A/\mu s$ |  | 330 | ns |
| $I_{RM}$ |                                                |  | 15  | A  |

Note 1: Pulse test,  $t \leq 300\mu s$ , duty cycle,  $d \leq 2\%$ .

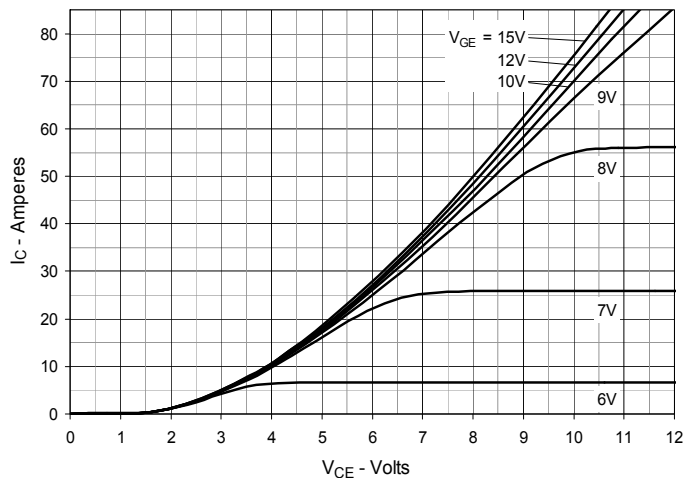
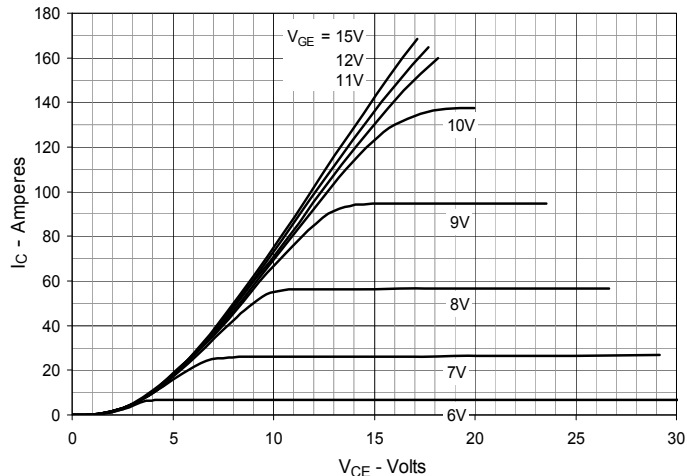
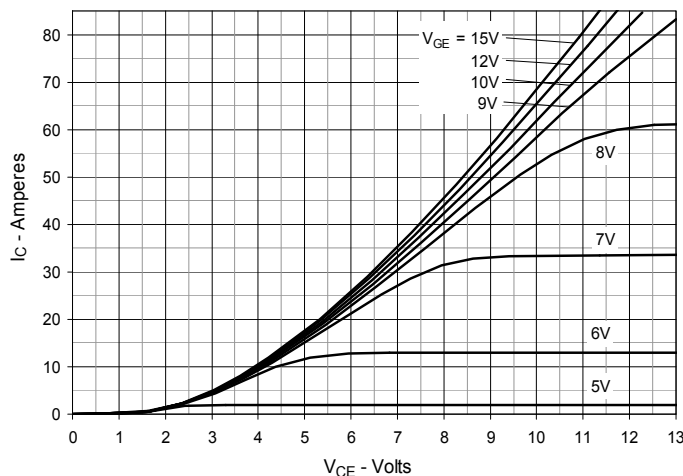
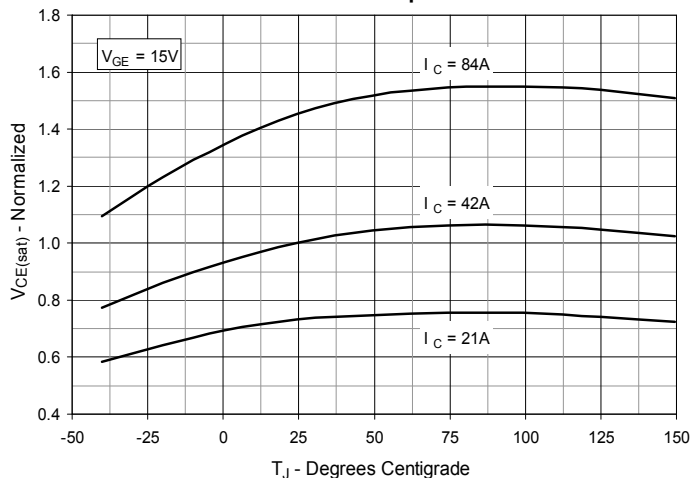
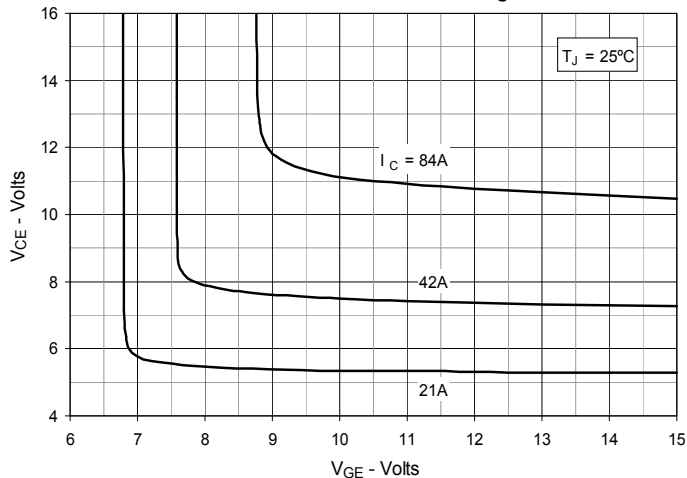
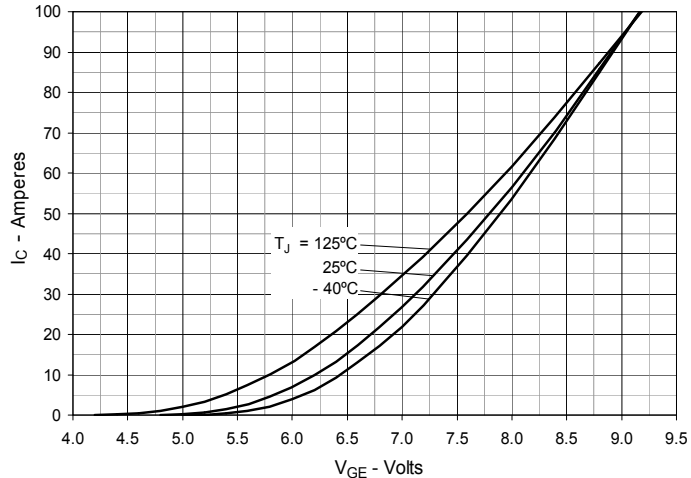
## PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

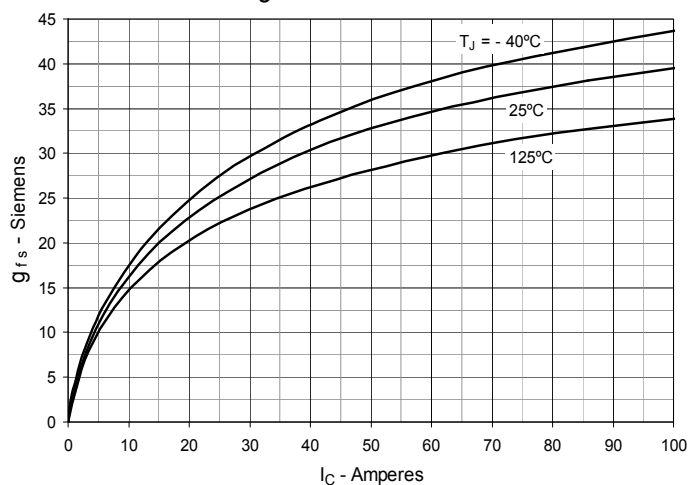
IXYS Reserves the Right to Change Limits, Test Conditions and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

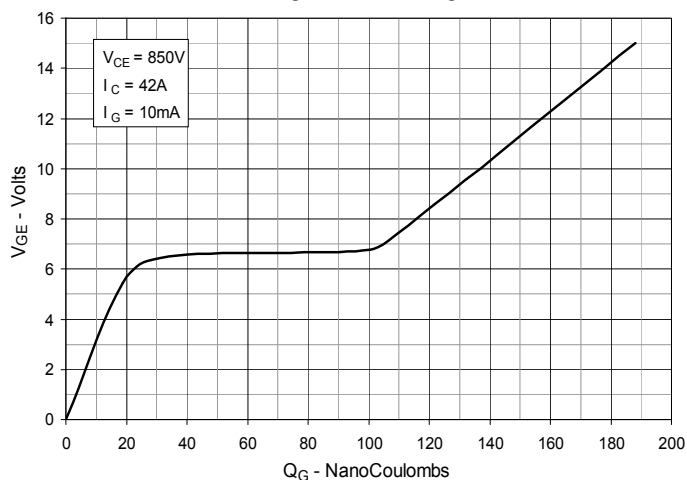
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|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** 

**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**

**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**

**Fig. 6. Input Admittance**


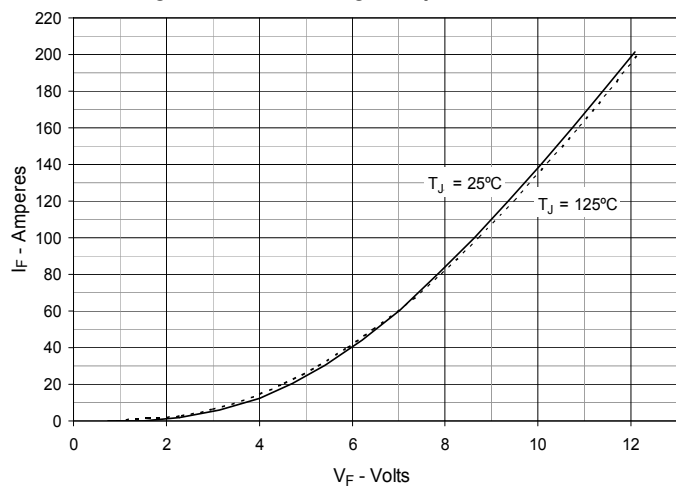
**Fig. 7. Transconductance**



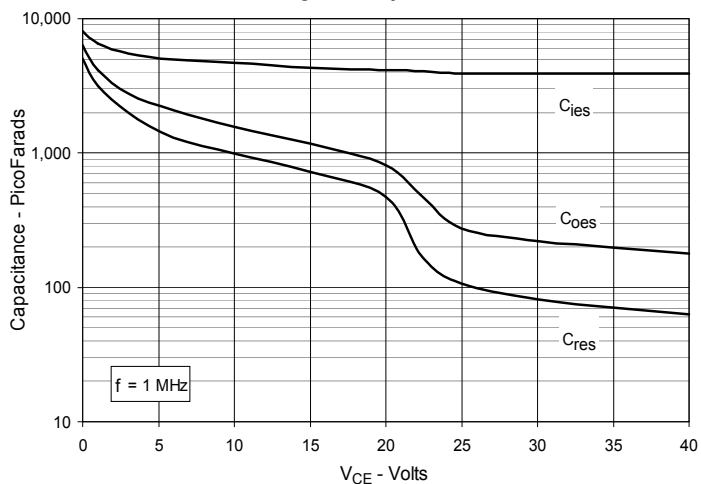
**Fig. 8. Gate Charge**



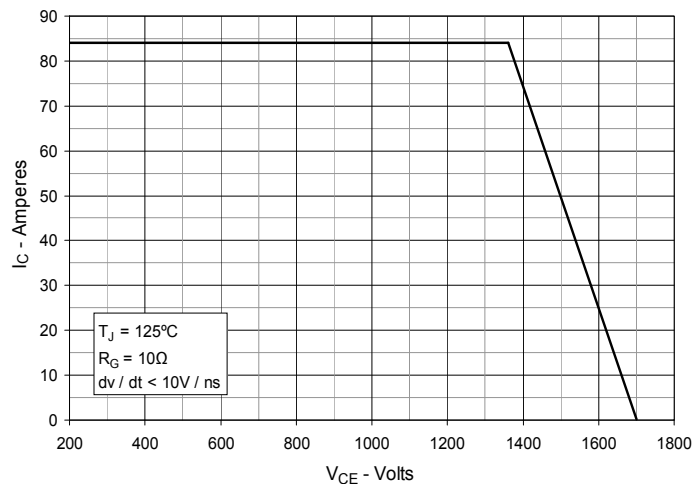
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



**Fig. 10. Capacitance**



**Fig. 11. Reverse-Bias Safe Operating Area**



**Fig. 12. Maximum Transient Thermal Impedance**

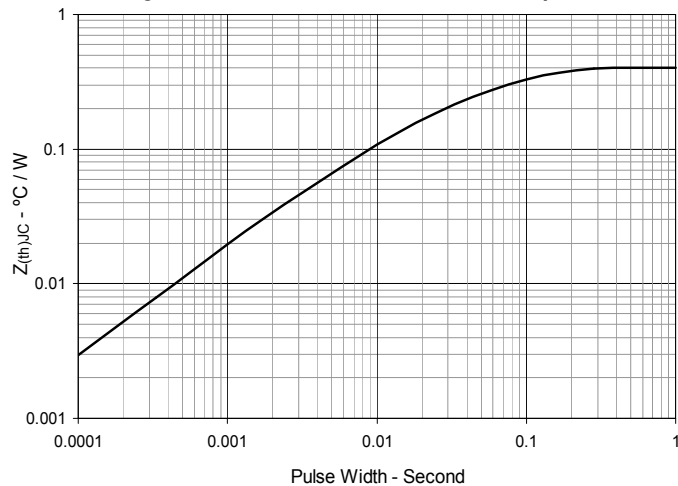


Fig. 13. Forward-Bias Safe Operating Area @  $T_C = 25^\circ\text{C}$

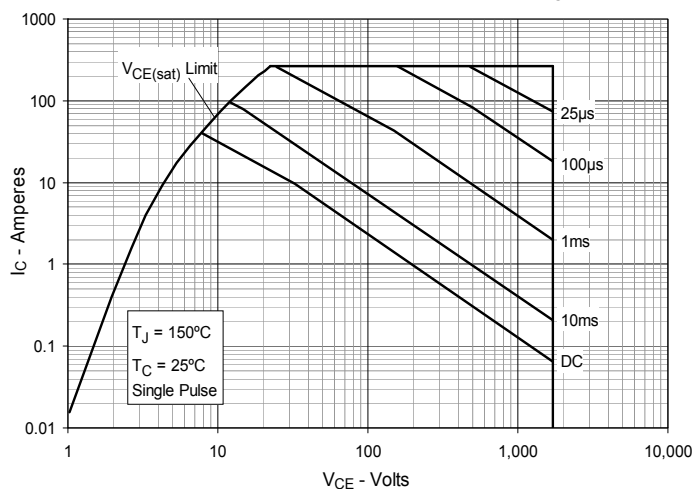


Fig. 14. Forward-Bias Safe Operating Area @  $T_C = 75^\circ\text{C}$

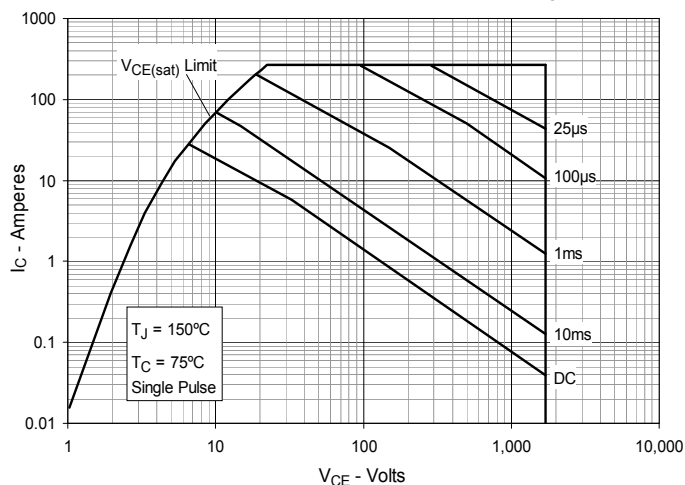


Fig. 15. Inductive Switching Energy Loss vs. Gate Resistance

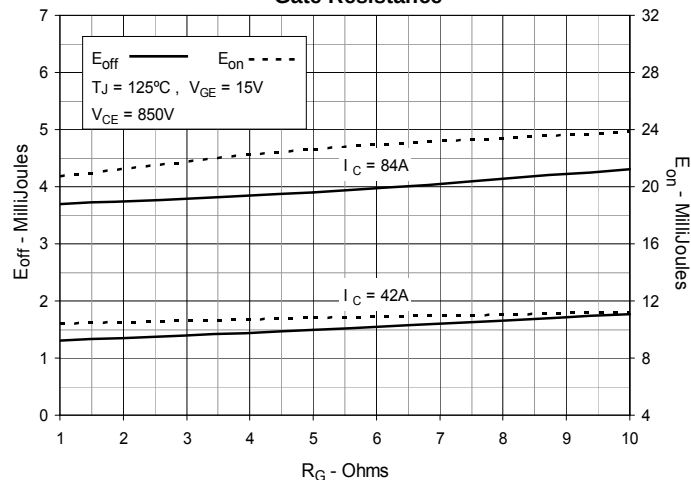


Fig. 16. Inductive Switching Energy Loss vs. Collector Current

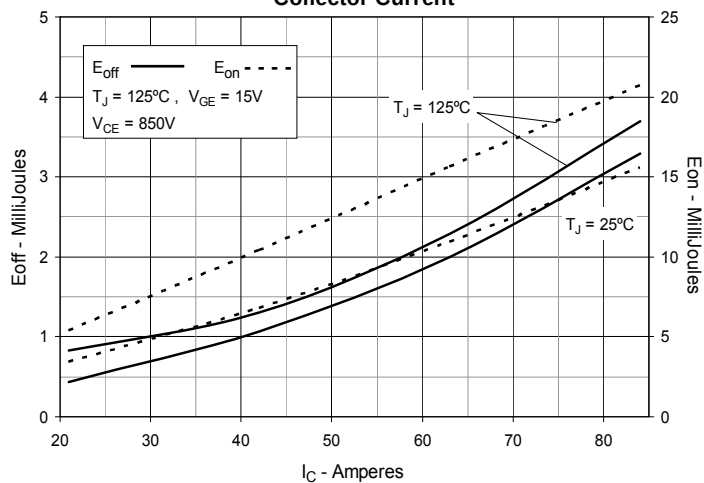


Fig. 17. Inductive Switching Energy Loss vs. Junction Temperature

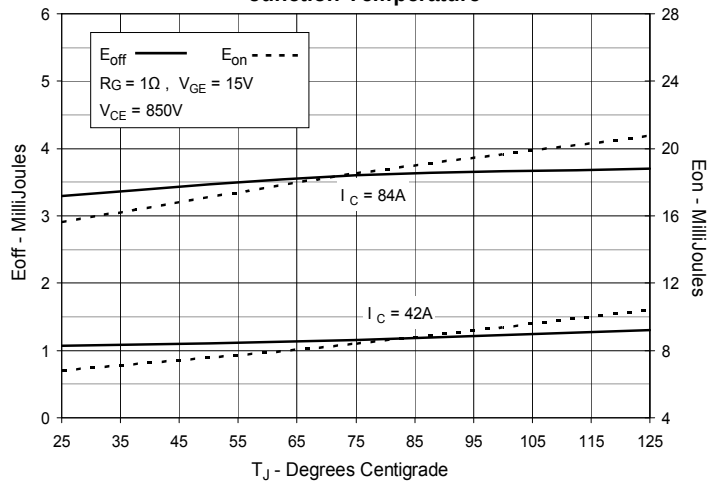
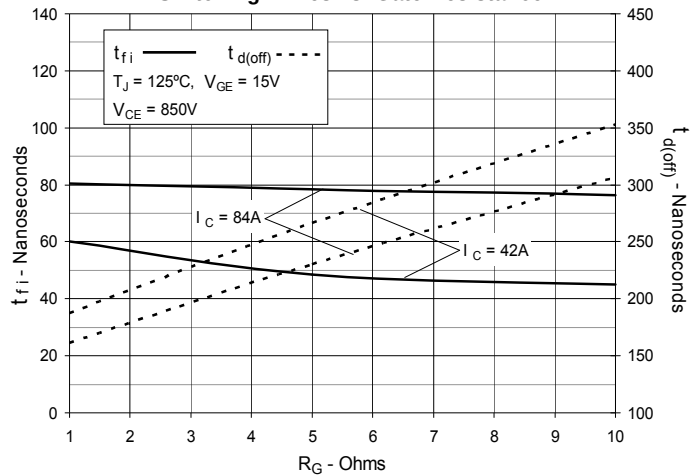
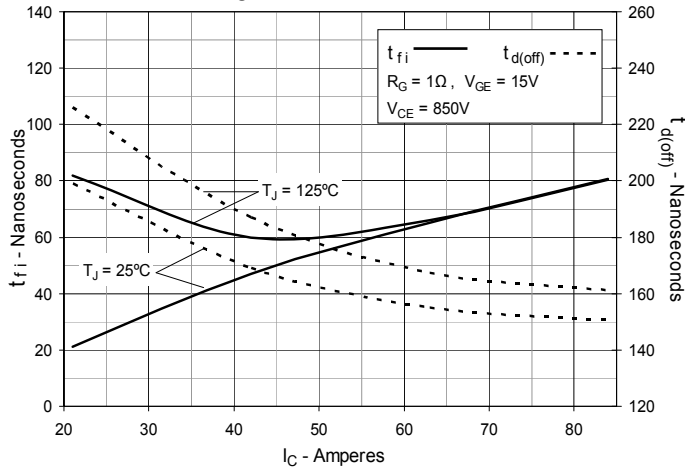


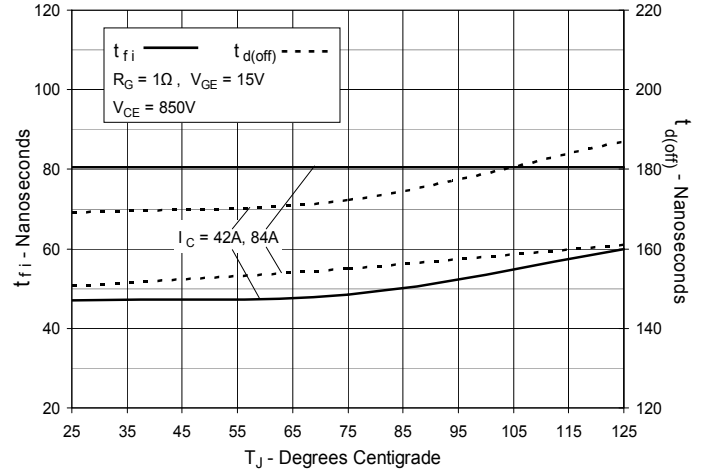
Fig. 18. Inductive Turn-off Switching Times vs. Gate Resistance



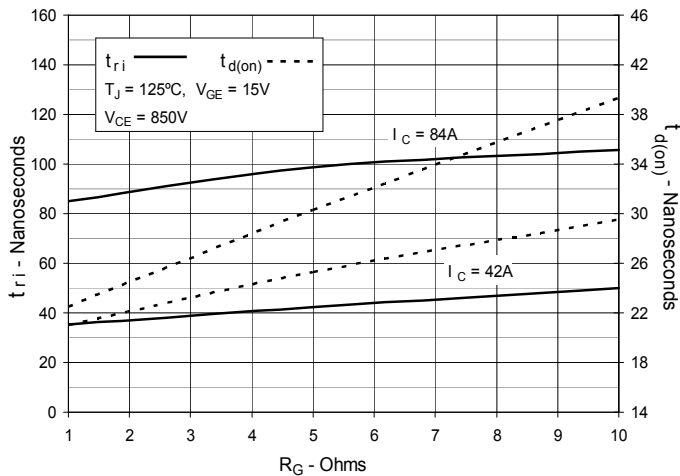
**Fig. 19. Inductive Turn-off  
Switching Times vs. Collector Current**



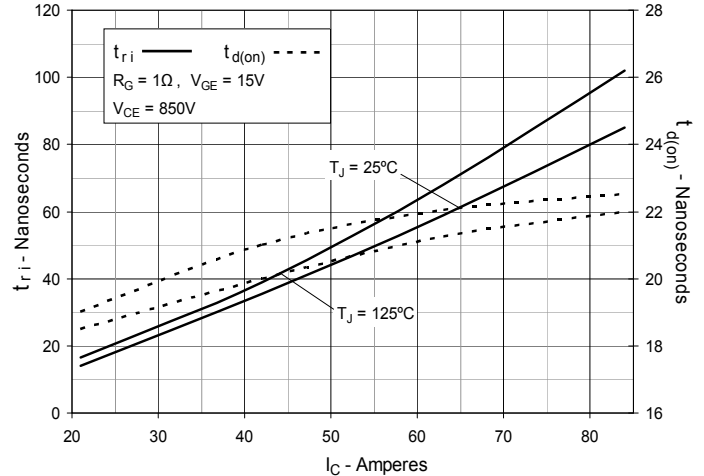
**Fig. 20. Inductive Turn-off  
Switching Times vs. Junction Temperature**



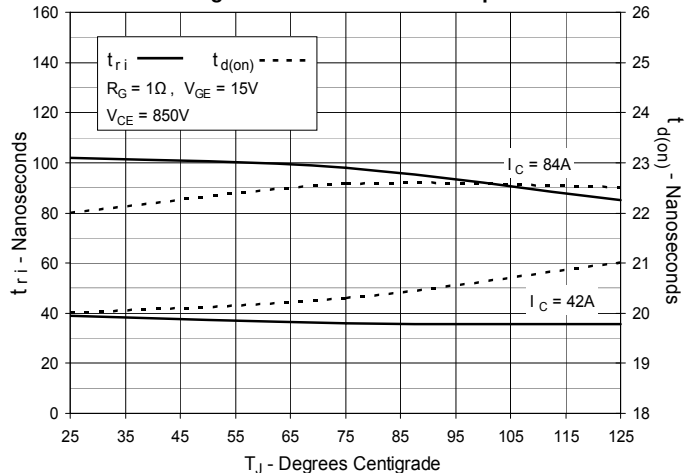
**Fig. 21. Inductive Turn-on Switching Times  
vs. Gate Resistance**



**Fig. 22. Inductive Turn-on Switching Times  
vs. Collector Current**



**Fig. 23. Inductive Turn-on  
Switching Times vs. Junction Temperature**



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